



CYPRESS

W234

Dual Direct Rambus™ Clock Generator

Features

- Differential clock source for Direct Rambus™ memory subsystem for up to 1.6-Gb/s serial data transfer rate
- Provide synchronization flexibility: the Rambus® Channel can optionally be synchronous to an external system or processor clock
- Power managed output allows Rambus Channel clock to be turned off to minimize power consumption for mobile applications
- Works with Cypress CY2210-2, CY2210-3, CY2215, W133, W158, W159, W161, and W167B to support Intel® architecture platforms
- Low-power CMOS design packaged in a 28-pin, 173-mil TSSOP package

Overview

The Cypress W234 provides dual channel differential clock signals for a Direct Rambus memory subsystem. It includes signals to synchronize the Direct Rambus Channel clock to an external system clock but can also be used in systems that do not require synchronization of the Rambus clock.

Key Specifications

Supply Voltage:..... $V_{DD} = 3.3V \pm 0.165V$

Operating Temperature:..... $0^{\circ}C$ to $+70^{\circ}C$

Input Threshold: 1.5V typical

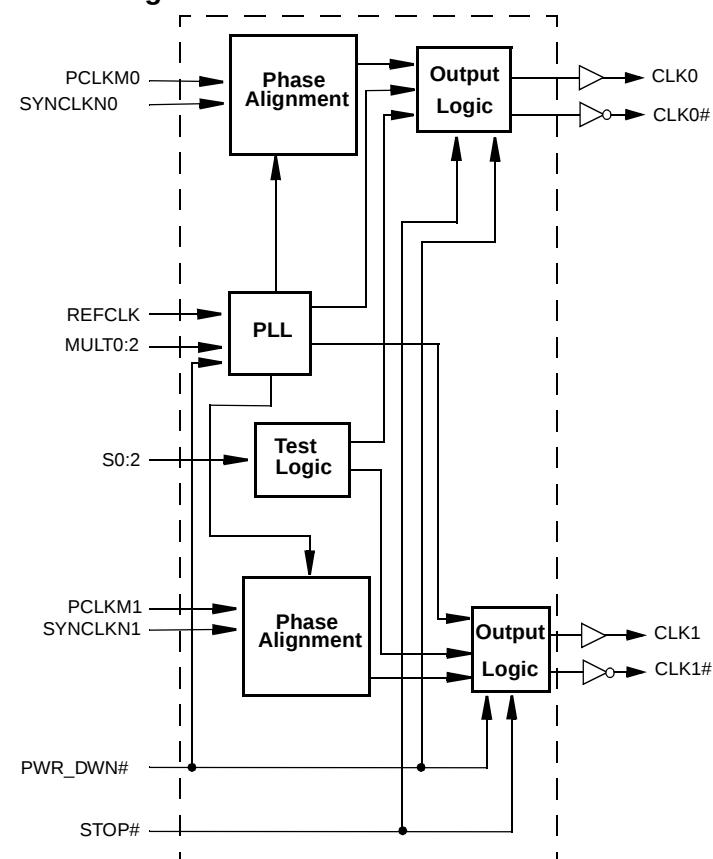
Maximum Input Voltage: $V_{DD} + 0.5V$

Maximum Input Frequency: 100 MHz

Output Duty Cycle: 40/60% worst case

Output Type: Rambus signaling level (RSL)

Block Diagram



Pin Configuration

VDDIR	1	28	S0
REFCLK	2	27	S1
VDD	3	26	S2
SYNCLKN0	4	25	GND
PCLKM0	5	24	CLK0#
GND	6	23	CLK0
VDD	7	22	VDD
GND	8	21	VDD
SYNCLKN1	9	20	CLK1
PCLKM1	10	19	CLK1#
VDD	11	18	GND
VDDIPD	12	17	MULT0
STOP#	13	16	MULT1
PWR_DWN#	14	15	MULT2

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Intel is a registered trademark of Intel Corporation.

Pin Definitions

Pin Name	Pin No.	Pin Type	Pin Description																																													
REFCLK	2	I	Reference Clock Input: Reference clock input, normally supplied by a system frequency synthesizer (Cypress W133).																																													
PCLKM0:1	5, 10	I	Phase Detector Input 0:1: The phase difference between this signal and SYN-CLKN is used to synchronize the Rambus Channel Clock with the system clock. Both PCLKM and SYNCLKN are provided by the Gear Ratio Logic in the memory controller. If the Gear Ratio Logic is not used, this pin would be connected to ground.																																													
SYNCLKN0:1	4, 9	I	Phase Detector Input 0:1: The phase difference between this signal and PCLKM is used to synchronize the Rambus Channel Clock with the system clock. Both PCLKM and SYNCLKN are provided by the Gear Ratio Logic in the memory controller. If the Gear Ratio Logic is not used, this pin would be connected to ground.																																													
STOP#	13	I	Clock Output Enable: When this input is driven to active LOW, it disables the differential Rambus Channel clocks.																																													
PWR_DWN#	14	I	Active LOW Power-Down: When this input is driven to active LOW, it disables the differential Rambus Channel clocks and places the W234 in Power-Down mode.																																													
MULT 0:2	17, 16, 15	I	PLL Multiplier Select: These inputs select the PLL prescaler and feedback dividers to determine the multiply ratio for the PLL for the input REFCLK. <table><tr><td>MULT0</td><td>MULT1</td><td>MULT2</td><td>A</td><td>B</td></tr><tr><td>0</td><td>0</td><td>0</td><td>4</td><td>1</td></tr><tr><td>0</td><td>0</td><td>1</td><td>9</td><td>2</td></tr><tr><td>0</td><td>1</td><td>0</td><td>6</td><td>1</td></tr><tr><td>0</td><td>1</td><td>1</td><td>TBD</td><td>TBD</td></tr><tr><td>1</td><td>0</td><td>0</td><td>8</td><td>3</td></tr><tr><td>1</td><td>0</td><td>1</td><td>16</td><td>3</td></tr><tr><td>1</td><td>1</td><td>0</td><td>8</td><td>1</td></tr><tr><td>1</td><td>1</td><td>1</td><td>TBD</td><td>TBD</td></tr></table>	MULT0	MULT1	MULT2	A	B	0	0	0	4	1	0	0	1	9	2	0	1	0	6	1	0	1	1	TBD	TBD	1	0	0	8	3	1	0	1	16	3	1	1	0	8	1	1	1	1	TBD	TBD
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CLK0, CLK0#, CLK1, CLK1#	23, 24, 20, 19	O	Complementary Output Clock: Differential Rambus Channel clock outputs.																																													
S0, S1, S2	28, 27, 26	I	Mode Control Input: These inputs control the operating mode of the W234. <table><tr><td>S0</td><td>S1</td><td>S2</td><td>MODE</td></tr><tr><td>0</td><td>0</td><td>0</td><td>Normal</td></tr><tr><td>1</td><td>0</td><td>0</td><td>Bypass</td></tr><tr><td>1</td><td>1</td><td>0</td><td>Test</td></tr><tr><td>0</td><td>0</td><td>1</td><td>Vendor Test A</td></tr><tr><td>1</td><td>0</td><td>1</td><td>Vendor Test B</td></tr><tr><td>1</td><td>1</td><td>1</td><td>Reserved</td></tr><tr><td>0</td><td>1</td><td>X</td><td>Output Test (OE)</td></tr></table>	S0	S1	S2	MODE	0	0	0	Normal	1	0	0	Bypass	1	1	0	Test	0	0	1	Vendor Test A	1	0	1	Vendor Test B	1	1	1	Reserved	0	1	X	Output Test (OE)													
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VDDIR	1	RefV	Reference for Refclk: Voltage reference for input reference clock.																																													
VDDIPD	12	RefV	Reference for Phase Detector: Voltage reference for phase detector inputs and STOP#.																																													
VDD	3, 7, 11, 21, 22	P	Power Connection: Power supply for core logic and output buffers. Connected to 3.3V supply.																																													
GND	6, 8, 18, 25	G	Ground Connection: Connect all ground pins to the common system ground plane.																																													

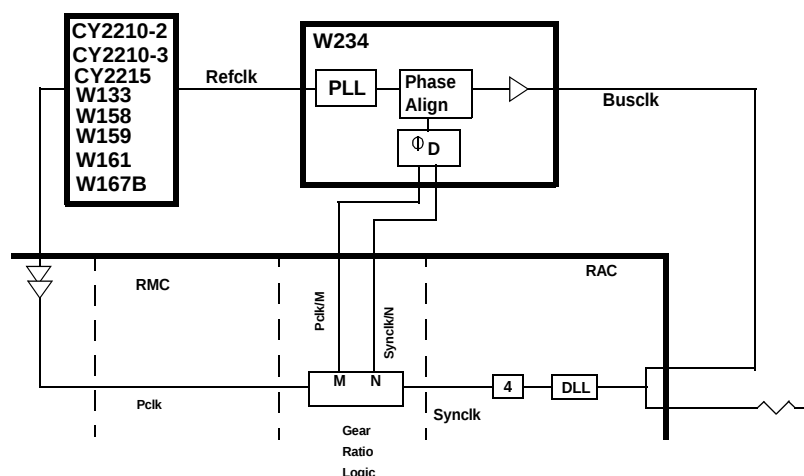


Figure 1. DDLL System Architecture

DDLL System Architecture and Gear Ratio Logic

Figure 1 shows the Distributed Delay Lock Loop (DDLL) system architecture, including the main system clock source, the Direct Rambus clock generator (DRCG), and the core logic that contains the Rambus Access Cell (RAC), the Rambus Memory Controller (RMC), and the Gear Ratio Logic. (This diagram abstractly represents the differential clocks as a single Busclk wire.)

The purpose of the DDLL is to frequency-lock and phase-align the core logic and Rambus clocks (PCLK and SYNCCLK) at the RMC/RAC boundary in order to allow data transfers without incurring additional latency. In the DDLL architecture, a PLL is used to generate the desired Busclk frequency, while a distributed loop forms a DLL to align the phase of Pclk and Syncclk at the RMC/RAC boundary.

The main clock source drives the system clock (Pclk) to the core logic, and also drives the reference clock (Refclk) to the DRCG. For typical Intel architecture platforms, Refclk will be half the CPU front side bus frequency. A PLL inside the DRCG multiplies Refclk to generate the desired frequency for Busclk, and Busclk is driven through a terminated transmission line (Rambus Channel). At the mid-point of the channel, the RAC senses Busclk using its own DLL for clock alignment, followed by a fixed divide-by-4 that generates Syncclk.

Pclk is the clock used in the memory controller (RMC) in the core logic, and Syncclk is the clock used at the core logic inter-

face of the RAC. The DDLL together with the Gear Ratio Logic enables users to exchange data directly from the Pclk domain to the Syncclk domain without incurring additional latency for synchronization. In general, Pclk and Syncclk can be of different frequencies, so the Gear Ratio Logic must select the appropriate M and N dividers such that the frequencies of Pclk/M and Syncclk/N are equal. In one interesting example, Pclk=133 MHz, Syncclk=100 MHz, and M=4 while N=3, giving Pclk/M=Syncclk/N=33 MHz. This example of the clock waveforms with the Gear Ratio Logic is shown in Figure 2.

The output clocks from the Gear Ratio Logic, Pclk/M, and Syncclk/N, are output from the core logic and routed to the DRCG Phase Detector (ϕ_D) inputs. The routing of Pclk/M and Syncclk/N must be matched in the core logic as well as on the board.

After comparing the phase of Pclk/M vs. Syncclk/N, the DRCG Phase Detector (ϕ_D) drives a phase aligner that adjusts the phase of the DRCG output clock, Busclk. Since everything else in the distributed loop is fixed delay, adjusting Busclk adjusts the phase of Syncclk and thus the phase of Syncclk/N. In this manner the distributed loop adjusts the phase of Syncclk/N to match that of Pclk/M, nulling the phase error at the input of the DRCG Phase Detector (ϕ_D). When the clocks are aligned, data can be exchanged directly from the Pclk domain to the Syncclk domain.

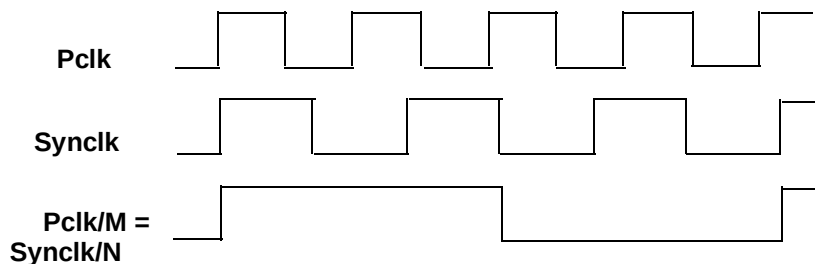


Figure 2. Gear Ratio Timing Diagram

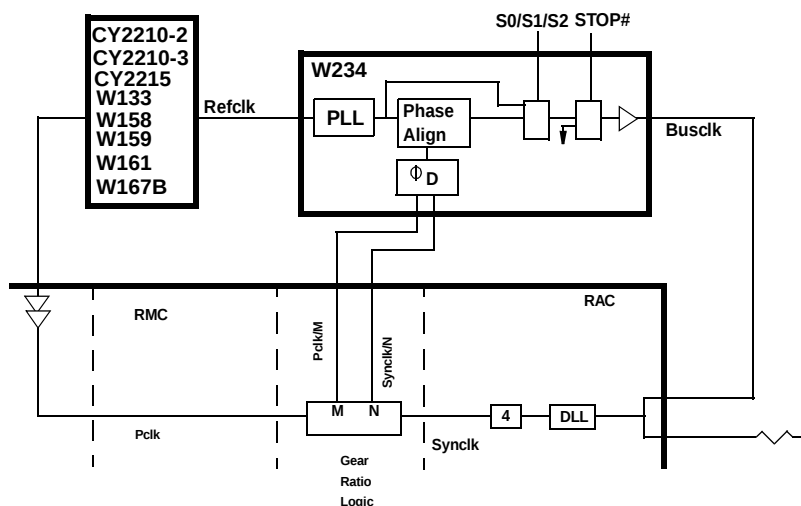


Figure 3. DDLL Including Details of DRCG

Phase Detector Signals

The DRCG Phase Detector (Φ_D) receives two inputs from the core logic, PCLKM (Pclk/M) and SYNCLKN (Synclk/N). The M and N dividers in the core logic are chosen so that the frequencies of PCLKM and SYNCLKN are identical. The Phase Detector (Φ_D) detects the phase difference between the two input clocks, and drives the DRCG Phase Aligner to null the input phase error through the distributed loop. When the loop is locked, the input phase error between PCLKM and SYNCLKN is within the specification $t_{ERR,PD}$ given in Table 13 after the lock time given in the State Transition Section.

The Phase Detector (Φ_D) aligns the rising edge of PCLKM to the rising edge of SYNCLKN. The duty cycle of the phase detector input clocks will be within the specification $DC_{IN,PD}$ given in Table 12. Because the duty cycles of the two phase detector input clocks will not necessarily be identical, the falling edges of PCLKM and SYNCLKN may not be aligned when the rising edges are aligned.

The voltage levels of the PCLKM and SYNCLKN signals are determined by the controller. The pin VDDIPD is used as the voltage reference for the phase detector inputs and should be connected to the output voltage supply of the controller. In some applications, the DRCG PLL output clock will be used directly, by bypassing the Phase Aligner. If PCLKM and SYNCLKN are not used, those inputs must be grounded.

Selection Logic

Table 1 shows the logic for selecting the PLL prescaler and feedback dividers to determine the multiply ratio for the PLL from the input Refclk. Divider A sets the feedback and divider B sets the prescaler, so the PLL output clock frequency is set by: $PLLCLK = Refclk * A/B$.

Table 1. PLL Divider Selection

MULT0	MULT1	MULT2	A	B
0	0	0	4	1
0	0	1	9	2
0	1	0	6	1
0	1	1	TBD	
1	0	0	8	3
1	0	1	16	3
1	1	0	8	1
1	1	1	TBD	

Table 2 shows the logic for enabling the clock outputs, using the STOP# input signal. When STOP# is HIGH, the DRCG is in its normal mode, and CLK and CLK# are complementary outputs following the Phase Aligner output (PACLK). When STOP# is LOW, the DRCG is in the Clk Stop mode, the output clock drivers are disabled (set to Hi-Z), and the CLK and CLK# settle to the DC voltage $V_{X,STOP}$ as given in Table 13. The level of $V_{X,STOP}$ is set by an external resistor network.

Table 2. Clk Stop Mode Selection

Mode	STOP#	CLK	CLK#
Normal	1	PACLK	PACLK#
Clk Stop	0	$V_{X,STOP}$	$V_{X,STOP}$

Table 3 shows the logic for selecting the Bypass and Test modes. The select bits, S0, S1, and S2 control the selection of these modes. The Bypass mode brings out the full-speed PLL output clock, bypassing the Phase Aligner. The Test mode brings the REFCLK input all the way to the output, bypassing both the PLL and the Phase Aligner. In the Output Test mode (OE), both the CLK and CLK# outputs are put into a high-impedance state (Hi-Z). This can be used for component testing and for board-level testing.

Table 3. Bypass and Test Mode Selection

Mode	S0	S1	S2	By Pclk (int.)	CLK	CLK#
Normal	0	0	0	Gnd	PAClk	PAClk#
Bypass	1	0	0	PLLCIk	PLLCIk	PLLCIk#
Test	1	1	0	RefClk	RefClk	RefClk#
Vendor Test A	0	0	1	-	-	-
Vendor Test B	1	0	1	-	-	-
Reserved	1	1	1	-	-	-
Output Test (OE)	0	1	X	-	Hi-Z	RefClk#

Table 4 shows the logic for selecting the Power-Down mode, using the PWR_DWN# input signal. PWR_DWN# is active LOW (enabled when 0). When PWR_DWN# is disabled, the DRCG is in its normal mode. When PWR_DWN# is enabled, the DRCG is put into a powered-off state, and the CLK and CLK# outputs are three-stated.

Table 4. PWR_DWN# Mode Selection

Mode	PWR_DWN#	CLK	CLK#
Normal	1	PAClk	PAClk#
Power-Down	0	GND	GND

Table of Frequencies and Gear Ratios

Table 5 shows several supported Pclk and Busclk frequencies, the corresponding A and B dividers required in the DRCG PLL,

Table 5. Frequencies, Dividers, and Gear Ratios

Pclk	Refclk	Busclk	Syncclk	A	B	M	N	Ratio	F@PD
67	33	267	67	8	1	2	2	1.0	33
100	50	300	75	6	1	8	6	1.33	12.5
100	50	400	100	8	1	4	4	1.0	25
133	67	267	67	4	1	4	2	2.0	33
133	67	400	100	6	1	8	6	1.33	16.7

and the corresponding M and N dividers in the gear ratio logic. The column Ratio gives the Gear Ratio as defined $Pclk/Syncclk$ (same as M and N). The column F@PD gives the divided down frequency (in MHz) at the Phase Detector (ϕ_D), where $F@PD = PCLK/M = SYNCCLK/N$.

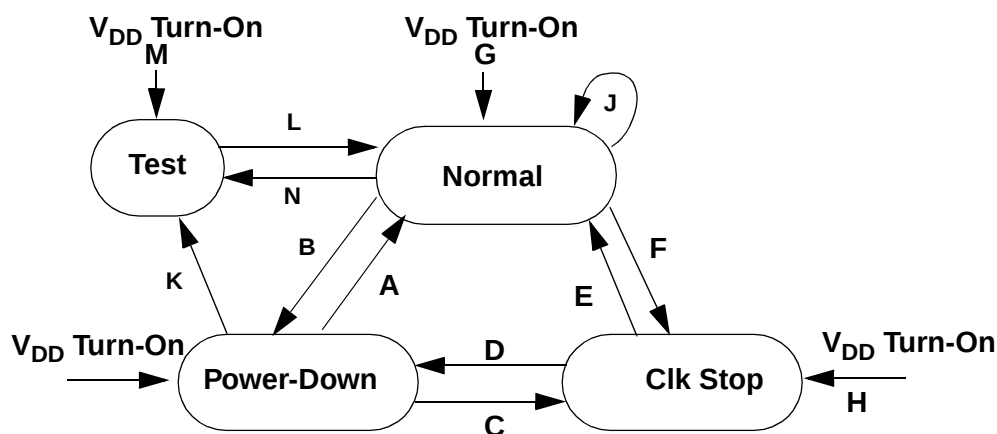
State Transitions

The clock source has three fundamental operating states. Figure 4 shows the state diagram with each transition labelled A through H. Note that the clock source output may NOT be glitch-free during state transitions.

Upon powering up the device, the device can enter any state, depending on the settings of the control signals, PWR_DWN# and STOP#.

In Power-Down mode, the clock source is powered down with the control signal, PWR_DWN#, equal to 0. The control signals S0, S1 and S2 must be stable before power is applied to the device, and can only be changed in Power-Down mode (PWR_DWN#=0). The reference inputs, VDDIR and VDDIPD, may remain on or may be grounded during the Power-Down mode.

The control signals MULT0, MULT1, and MULT2 can be used in two ways. If they are changed during Power-Down mode, then the Power-Down transition timings determine the settling time of the DRCG. However, the MULT0, MULT1, and MULT2 control signals can also be changed during Normal mode. When the MULT control signals are "hot swapped" in this manner, the MULT transition timings determine the settling time of the DRCG.


Figure 4. Clock Source State Diagram

In Clk Stop mode, the clock source is on, but the output is disabled (STOP# asserted). The VDDIPD reference input may remain on or may be grounded during the Clk Stop mode. The VDDIR reference input must remain on during the Clk Stop mode.

In Normal mode, the clock source is on, and the output is enabled.

Table 6 lists the control signals for each state.

Table 6. Control Signals for Clock Source States

State	PWR_DWN#	STOP#	Clock Source	Output Buffer
Power-Down	0	X	OFF	Ground
Clk Stop	1	0	ON	Disabled
Normal	1	1	ON	Enabled

Timing Diagrams

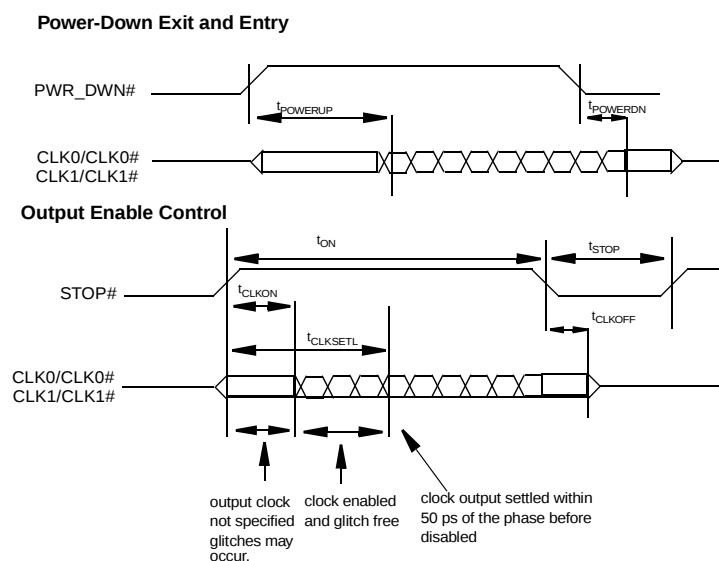


Figure 5. State Transition Timing Diagrams

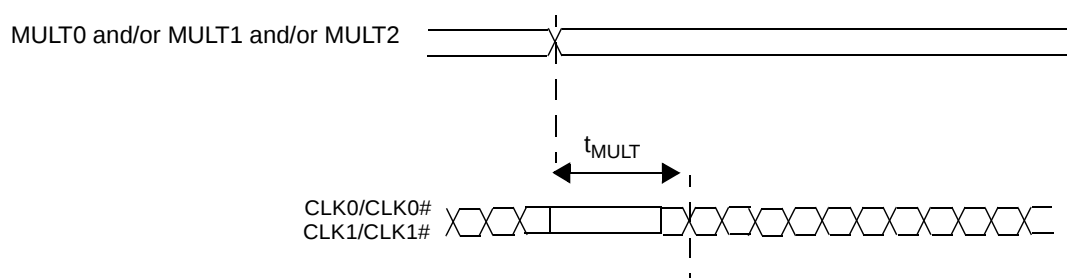


Figure 6. Multiply Transition Timing

Table 7. State Transition Latency Specifications

Transition	From	To	Transition Latency		Description
			Symbol	Max.	
A	Power-Down	Normal	t_{POWERUP}	3 ms	Time from PWR_DWN# to rising edge CLK/CLK# output settled (excluding $t_{\text{DIS-TLOCK}}$)
C	Power-Down	Clk Stop	t_{POWERUP}	3 ms	Time from PWR_DWN# rising edge until the internal PLL and clock has turned ON and settled.
K	Power-Down	Test	t_{POWERUP}	3 ms	Time from PWR_DWN# rising edge to CLK/CLK# output settled (excluding $t_{\text{DIS-TLOCK}}$).
G	VDD ON	Normal	t_{POWERUP}	3 ms	Time from VDD is applied and settled until CLK/CLK# output settled (excluding $t_{\text{DIS-TLOCK}}$).
H	VDD ON	Clk Stop	t_{POWERUP}	3 ms	Time from VDD is applied and settled until internal PLL and clock has turned ON and settled.
M	VDD ON	Test	t_{POWERUP}	3 ms	Time from VDD is applied and settled until internal PLL and clock has turned ON and settled.
J	Normal	Normal	t_{MULT}	1 ms	Time from when MULT0, MULT1, or MULT2 changed until CLK/CLK# output resettled (excluding t_{DISTLOCK}).
E	Clk Stop	Normal	t_{CLKON}	10 ns	Time from STOP# rising edge until CLK/CLK# provides glitch-free clock edges.
E	Clk Stop	Normal	t_{CLKSETL}	20 cycles	Time from STOP# rising edge to CLK/CLK# output settled to within 50 ps of the phase before CLK/CLK# was disabled.
F	Normal	Clk Stop	t_{CLKOFF}	5 ns	Time from STOP# falling edge to CLK/CLK# output disabled.
L	Test	Normal	t_{CTL}	3 ms	Time from when S0, S1, or S2 is changed until CLK/CLK# output has resettled (excluding t_{DISTLOCK}).
N	Normal	Test	t_{CTL}	3 ms	Time from when S0, S1, or S2 is changed until CLK/CLK# output has resettled (excluding t_{DISTLOCK}).
B,D	Normal or Clk Stop	PWR_DWN#	t_{POWERDN}	1 ms	Time from PWR_DWN# falling edge to the device in PWR_DWN#.

Figure 5 shows that the CLK Stop to Normal transition goes through three phases. During t_{CLKON} , the clock output is not specified and can have glitches. For $t_{\text{CLKON}} < t_{\text{CLKSETL}}$, the clock output is enabled and must be glitch-free. For t_{CLKSETL} , the clock output phase must be settled to within

50 ps of the phase before the clock output was disabled. At this time, the clock output must also meet the voltage and timing specifications of Table 13. The outputs are in a high-impedance state during the Clk Stop mode.

Table 8. Distributed Loop Lock Time Specification

Symbol	Min.	Max.	Unit	Description
t_{DISTLOCK}		5	ms	Time from when CLK/CLK# output is settled to when the phase error between SYNCLKN and PCLKM falls within the $t_{\text{ERR,PD}}$ spec in Table 13.

Table 9. Supply and Reference Current Specification

Parameter	Description	Min.	Max.	Unit
$I_{\text{POWERDOWN}}$	"Supply" current in Power-Down state (PWR_DWN#=0)	--	1.2	mA
I_{CLKSTOP}	"Supply" current in Clk Stop state (STOP#=0)	--	175	mA
I_{NORMAL}	"Supply" current in Normal state (STOP#=1, PWR_DWN#=1)	--	225	mA
$I_{\text{REF,PWDN}}$	Current at VDDIR or VDDIPD reference pin in PWR_DWN# state (PWR_DWN#=0)	--	50	μA
$I_{\text{REF,NORM}}$	Current at VDDIR or VDDIPD reference pin in Normal or Clk Stop state (PWR_DWN#=1)	--	4	mA

Table 10 represents stress ratings only, and functional operation at the maximums is not guaranteed.

Table 10. Absolute Maximum Ratings

Parameter	Description	Min.	Max.	Unit
$V_{\text{DD, ABS}}$	Max. voltage on VDD with respect to ground	-0.5	4.0	V
$V_{\text{I, ABS}}$	Max. voltage on any pin with respect to ground	-0.5	VDD+0.5	V

Table 11 gives the nominal values of the external components and their maximum acceptable tolerance, assuming $Z_{\text{CH}}=28\Omega$.

Table 11. External Component Values

Parameter	Description	Min.	Max.	Unit
R_{S}	Serial Resistor	39	$\pm 5\%$	Ω
R_{P}	Parallel Resistor	51	$\pm 5\%$	Ω
C_{F}	Edge Rate Filter Capacitor	4–15 ^[1]	$\pm 10\%$	pF
C_{MID}	AC Ground Capacitor	0.1	$\pm 20\%$	μF

Note:

1. Do not populate C_{F} . Leave pads for future use.

Table 12. Operating Conditions

Parameter	Description	Min.	Max.	Unit
VDD	Supply Voltage	3.135	3.465	V
T _A	Ambient Operating Temperature	0	70	°C
t _{CYCLE,IN}	Refclk Input Cycle Time	10	40	ns
t _{J,IN}	Input Cycle-to-Cycle Jitter ^[2]	–	250	ps
DC _{IN}	Input Duty Cycle over 10,000 Cycles	40	60	%t _{CYCLE}
FM _{IN}	Input Frequency of Modulation	30	33	kHz
PM _{IN} ^[3]	Modulation Index for Triangular Modulation	–	0.6	%
	Modulation Index for Non-Triangular Modulation	–	0.5 ^[4]	%
t _{CYCLE,PD}	Phase Detector Input Cycle Time at PCLKM & SYNCLKN	30	100	ns
t _{ERR,INIT}	Initial Phase error at Phase Detector Inputs	–0.5	0.5	t _{CYCLE,PD}
DC _{IN,PD}	Phase Detector Input Duty Cycle over 10,000 Cycles	25	75	t _{CYCLE,PD}
t _{I,SR}	Input Slew Rate (measured at 20%-80% of input voltage) for PCLKM, SYNCLKN, and REFCLK	1	4	V/ns
C _{IN,PD}	Input Capacitance at PCLKM, SYNCLKN, and REFCLK ^[5]	–	7	pF
ΔC _{IN,PD}	Input Capacitance matching at PCLKM and SYNCLKN ^[5]	–	0.5	pF
C _{IN,CMOS}	Input Capacitance at CMOS pins (excluding PCLKM, SYNCLKN, and REFCLK) ^[5]	–	10	pF
V _{IL}	Input (CMOS) Signal Low Voltage	–	0.3	VDD
V _{IH}	Input (CMOS) Signal High Voltage	0.7	–	VDD
V _{IL,R}	Refclk Input Low Voltage	–	0.3	V _{DDIR}
V _{IH,R}	Refclk Input High Voltage	0.7	–	V _{DDIR}
V _{IL,PD}	Input Signal Low Voltage for PD Inputs and STOP#	–	0.3	V _{DDIPD}
V _{IH,PD}	Input Signal High Voltage for PD Inputs and STOP#	0.7	–	V _{DDIPD}
V _{DDIR}	Input Supply Reference for REFCLK	1.235	3.465	V
V _{DDIPD}	Input Supply Reference for PD Inputs	1.235	2.625	V

Notes:

- Refclk jitter measured at V_{DDIR} (nom)/2.
- If input modulation is used: input modulation is allowed but not required.
- The amount of allowed spreading for any non-triangular modulation is determined by the induced downstream tracking skew, which cannot exceed the skew generated by the specified 0.6% triangular modulation. Typically, the amount of allowed non-triangular modulation is about 0.5%.
- Capacitance measured at Freq=1 MHz, DC bias=0.9V and V_{AC}<100 mV.

Table 13. Device Characteristics

Parameter	Description	Min.	Max.	Unit
t_{CYCLE}	Clock Cycle Time	2.5	3.75	ns
t_j	Cycle-to-Cycle Jitter at CLK/CLK# ^[6]	-	60	ps
	Total Jitter over 2, 3, or 4 Clock Cycles ^[6]	-	75	ps
	266-MHz Cycle-to-Cycle Jitter ^[7]	-	60	ps
	266-MHz Total Jitter over 2, 3, or 4 Clock Cycles ^[7]	-	75	ps
$V_{\text{X,STOP}}$	Output Voltage during Clk Stop (STOP#=0)	1.1	2.0	V
V_{X}	Differential Output Crossing-Point Voltage	1.3	1.8	V
V_{COS}	Output Voltage Swing (p-p single-ended) ^[8]	1.1	1.5	V
V_{OH}	Output High Voltage	-	2.5	V
V_{OL}	Output Low voltage	0.6	-	V
$I_{\text{OZ,STOP}}$	Output Current during Clk Stop (STOP# = 0)	-	500	μA
DC	Output Duty Cycle over 10,000 Cycles	40	60	% t_{CYCLE}
$t_{\text{DC,ERR}}$	Output Cycle-to-Cycle Duty Cycle Error	-	50	ps
$t_{\text{R}}, t_{\text{F}}$	Output Rise and Fall Times (measured at 20%–80% of output voltage)	300	550	ps
$t_{\text{CR,CF}}$	Difference between Output Rise and Fall Times on the Same Pin of a Single Device (20%–80%)	-	100	ps

Notes:

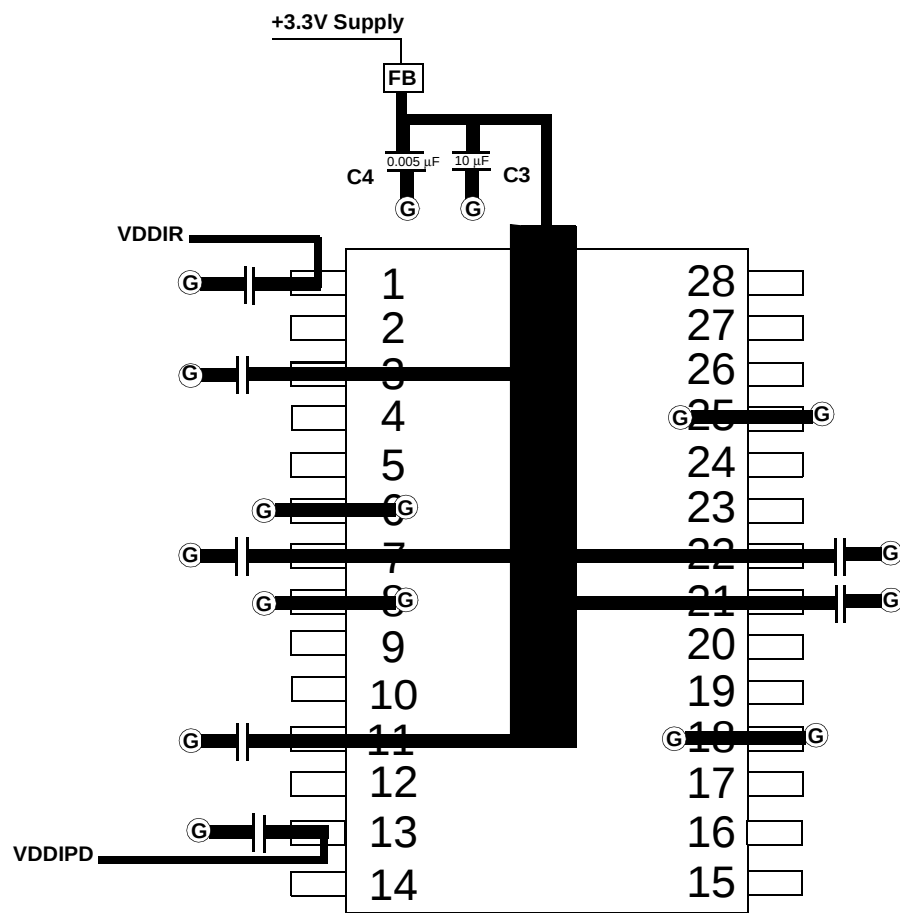
6. Output Jitter spec measured at $t_{\text{CYCLE}} = 2.5$ ns.
7. Output Jitter Spec measured at $t_{\text{CYCLE}} = 3.75$ ns.
8. $V_{\text{COS}} = V_{\text{OH}} - V_{\text{OL}}$.

Ordering Information

Ordering Code	Package Name	Package Type
W234	X	28-pin TSSOP (173 mils)

Document #: 38-00921-*A

Layout Example

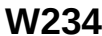


Internal Power Supply Plane

FB = Dale ILB1206 - 300 (300Ω @ 100 MHz)

ⓐ = VIA to GND plane layer

All Bypass cap = 0.1 Ceramic XR7



28-Pin Thin Small Shrink Outline Package (TSSOP, 173 mils)

NOTES

THIS TABLE IN MILLIMETERS

COMMON DIMENSIONS			NOTE VARIATIONS	4 D			6 N
MIN.	NOM.	MAX.		MIN.	NOM.	MAX.	
A		1 10	AA	2.90	3 00	3 10	5
A	0.05	0.10	AB	4.90	5 00	5 10	14
A	0.85	0.90	AC	4.90	5 00	5 10	16
a	0.19	0.20	AD	6.40	6 50	6 60	20
b1	0.19	0.22	AE	7.70	7 80	7 90	24
c	0.090	0.20	AF	9.60	9 70	9 80	28
c1	0.090	0.135					
D	SEE VARIATIONS		4				
E	4.30	4.40	4				
e	0.65 BSC						
H	6.25	6.40					
L	0.50	0.90	5				
N	SEE VARIATIONS		6				
	0°	4°	8°				

THIS TABLE IN INCHES

COMMON DIMENSIONS				NOTE VARIATIONS		4 D		6 N	
	MIN.	NOM.	MAX.		MIN.	NOM.	MAX.		
A			C433		AA	114	118	122	5
A	.002	.004	.006		AB	193	197	201	14
a	.0335	.0354	.0374		AC	193	197	201	16
A	.0075		C118	8	AD	252	256	260	20
b1	.0075	.0087	.0096		AE	303	307	311	24
c	.0035		C079		AF	378	382	386	28
c1	.0035	.0050	.0053						
D	SEE VARIATIONS			4					
E	.169	.173	.177						
e		.0256	BSC	4					
H	.246	.252	.256						
L	.020	.024	.028	5					
N	SEE VARIATIONS			6					
i	0°	4°	8°						

VARIATION AF IS DESIGNED BUT NOT TOOLED

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